

### FEATURES

- Set of 4 narrow-band VCOs with consistent sensitivity vs. frequency
- RF and tuning ports common to all 4 VCOs
- RF output operates from fundamental oscillators with no subharmonic oscillations
- Up to 4 dBm RF output power
- Power mute capability
- No external resonator required
- 40-lead, 6 mm × 6 mm LFCSP

### APPLICATIONS

- Electronic test and measurement
- Industrial and medical instrumentation
- Point to point and multipoint radios
- Aerospace and defense
- Wireless communication infrastructure

### FUNCTIONAL BLOCK DIAGRAM

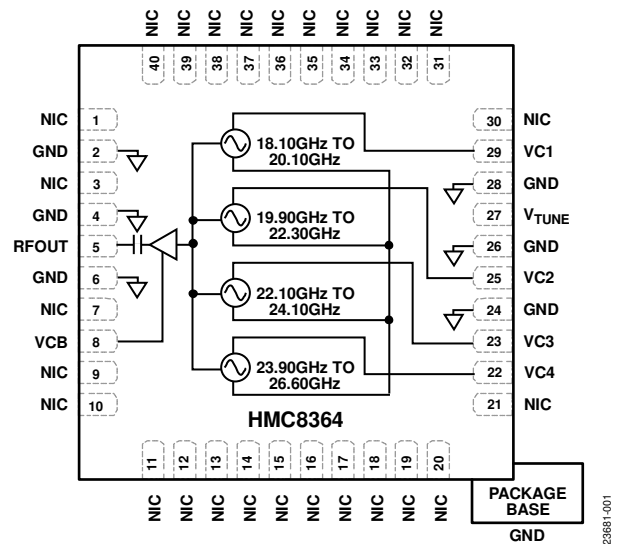


Figure 1.

### GENERAL DESCRIPTION

The HMC8364 is a gallium arsenide (GaAs), quadband, monolithic microwave integrated circuit (MMIC), voltage controlled oscillator (VCO) designed to offer wideband frequency capabilities without compromising phase noise performance. The device integrates four independent, narrow-band VCOs with overlapping frequency bands, operating at a fundamental frequency range of 18.10 GHz to 26.60 GHz. The consistent tuning sensitivity across all frequency bands simplifies the synthesizer loop filter design.

The tuning port is common to all VCO cores for a simpler design of the phase-locked loop (PLL) feedback path. The HMC8364 also offers a low typical current consumption of 99 mA for power sensitive applications.

The HMC8364 integrates resonators, negative resistance devices, and varactor diodes. The monolithic structure of the oscillator offers very low phase noise, optimal temperature stability, and is immune to vibration and process variation.

The four VCOs are packaged in a single, 6 mm × 6 mm, surface-mount lead frame chip scale package (LFCSP), and require no external matching components.

Combined with a high frequency, high performance PLL, the ADF41513, the HMC8364 offers a complete RF or microwave frequency generation solution.

## TABLE OF CONTENTS

Features .....	1	Interface Schematics .....	6
Applications .....	1	Typical Performance Characteristics .....	7
Functional Block Diagram .....	1	Band 1: 18.10 GHz to 20.10 GHz, $V_{CC} = 5\text{ V}$ .....	7
General Description .....	1	Band 2: 19.90 GHz to 22.30 GHz, $V_{CC} = 5\text{ V}$ .....	9
Revision History .....	2	Band 3: 22.10 GHz to 24.10 GHz, $V_{CC} = 5\text{ V}$ .....	11
Specifications .....	3	Band 4: 23.90 GHz to 26.60 GHz, $V_{CC} = 5\text{ V}$ .....	13
Absolute Maximum Ratings .....	5	Theory of Operation .....	15
Thermal Resistance .....	5	Applications Information .....	16
Electrostatic Discharge (ESD) Ratings .....	5	Outline Dimensions .....	17
ESD Caution .....	5	Ordering Guide .....	17
Pin Configuration and Function Descriptions .....	6		

## REVISION HISTORY

9/2020—Revision A: Initial Version

## SPECIFICATIONS

$T_A = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$  and Band 1 to Band 4 supply voltage ( $V_{CC}$ ) = 5 V, buffer supply voltage ( $V_{CB}$ ) = 5 V, unless otherwise noted.

Table 1.

Parameter	Min	Typ	Max	Unit	Test Conditions/Comments
<b>RF OUTPUT CHARACTERISTICS</b>					
Frequency ( $f_{OUT}$ )					
Band 1	18.10		20.10	GHz	
Band 2	19.90		22.30	GHz	
Band 3	22.10		24.10	GHz	
Band 4	23.90		26.60	GHz	
Output Power ( $P_{OUT}$ )					
Band 1	-3	0	+4	dBm	
Band 2	-4	-0.5	+4	dBm	
Band 3	-4	+0.8	+4	dBm	
Band 4	-8	-1.5	+3	dBm	
$P_{OUT}$ with Buffer Amplifier Muted					Measured at $V_{CB} = 0\text{ V}$
Band 1		-20			
Band 2		-22			
Band 3		-21			
Band 4		-25			
Tuning Sensitivity					
Band 1		267		MHz/V	
Band 2		330		MHz/V	
Band 3		362		MHz/V	
Band 4		364		MHz/V	
Frequency Drift Rate					Drift specifications are not de-embedded to remove contribution from the board
Band 1		2.0		MHz/ $^{\circ}\text{C}$	
Band 2		2.3		MHz/ $^{\circ}\text{C}$	
Band 3		2.7		MHz/ $^{\circ}\text{C}$	
Band 4		3.1		MHz/ $^{\circ}\text{C}$	
Harmonic Content					
Second Harmonic		18		dBc	Worst measured value at typical
Frequency Pulling		0.45		MHz p-p	Worst measured value at typical
Frequency Pushing		65		MHz/V	Worst measured value at typical
Output Return Loss		8		dB	Worst measured value at typical
<b>POWER SUPPLIES</b>					
Supply Voltage	4.75	5.0	5.25	V	
Supply Current ( $I_{CC}$ )					
Band 1		83		mA	
Band 2		81		mA	
Band 3		87		mA	
Band 4		80		mA	
Buffer Amplifier		12		mA	
Total Supply Current		99	130	mA	Total supply current is for the output buffer and one VCO band; only one VCO band must be powered at a time
Tune Voltage	1.0		13.5	V	
Tune Port Leakage Current			60	$\mu\text{A}$	$V_{TUNE} = 13.5\text{ V}$ , where the maximum tune port leakage current is measured

<b>Parameter</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Unit</b>	<b>Test Conditions/Comments</b>
SINGLE SIDEBAND PHASE NOISE					
Band 1					
10 kHz		-66		dBc/Hz	
100 kHz		-95		dBc/Hz	
1 MHz		-122		dBc/Hz	
Band 2					
10 kHz		-65		dBc/Hz	
100 kHz		-92		dBc/Hz	
1 MHz		-120		dBc/Hz	
Band 3					
10 kHz		-62		dBc/Hz	
100 kHz		-91		dBc/Hz	
1 MHz		-118		dBc/Hz	
Band 4					
10 kHz		-62		dBc/Hz	
100 kHz		-89		dBc/Hz	
1 MHz		-118		dBc/Hz	

## ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
$V_{C1}$ to $V_{C4}$ , $V_{CB}$ <sup>1</sup>	5.5 V dc
$V_{TUNE}$	0 V to 14.5 V
Temperature	
Operating	–40°C to +85°C
Storage	–65°C to +150°C
Nominal Junction (to Maintain 1 Million Hours Mean Time to Failure (MTTF))	135°C
Peak Reflow (Moisture Sensitivity Level (MSL) 3 Rating)	260°C

<sup>1</sup> Only one VCO band must be powered at a time.  $V_{C1}$  to  $V_{C4}$  are the Band 1 to Band 4 supply voltages on the VC1 to VC4 pins, respectively.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

## THERMAL RESISTANCE

Thermal performance is directly linked to printed circuit board (PCB) design and operating environment. Careful attention to PCB thermal design is required.

$\theta_{JA}$  is the natural convection junction to ambient thermal resistance measured in a one cubic foot sealed enclosure.  $\theta_{JC}$  is the junction to case thermal resistance.

Table 3. Thermal Resistance

Package Type <sup>1</sup>	$\theta_{JA}$	$\theta_{JC}$	Unit
HCP-40-1	27.50	18.04	°C/W

<sup>1</sup> The thermal impedance simulated values are based on the JE51 standard using 2S2P on FR4 with four standard JEDEC vias (0.3 mm diameter, 0.025 mm plating, and 1.2 mm pitch).

## ELECTROSTATIC DISCHARGE (ESD) RATINGS

The following ESD information is provided for handling of ESD sensitive devices in an ESD protected area only.

Human body model (HBM) per JEDEC JS-001.

Charged device model (CDM) per ANSI/ESDA/JEDEC JS-002.

### ESD Ratings for HMC8364

Table 4. HMC8364, 40-Lead LFCSP

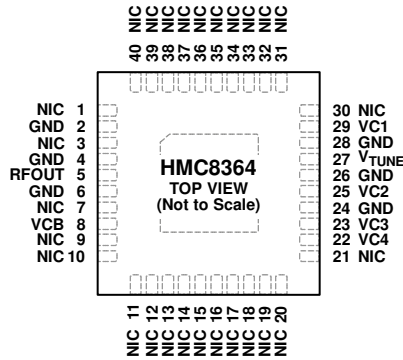
ESD Model	Withstand Threshold (V)	Class
HBM	±250	1A
CDM	±1000	C3

## ESD CAUTION



**ESD (electrostatic discharge) sensitive device.** Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

# PIN CONFIGURATION AND FUNCTION DESCRIPTIONS



**NOTE**  
 1. NIC = NO INTERNAL CONNECTION. HOWEVER, THESE PINS CAN BECONNECTED TO RF OR DC GROUND WITHOUT AFFECTING THE PERFORMANCE OF THE DEVICE.  
 2. EXPOSED PAD. THE PACKAGE BOTTOM HAS AN EXPOSED METAL PAD THAT MUST BE CONNECTED TO RF OR DC GROUND.

23881-002

Figure 2. Pin Configuration

Table 5. Pin Function Descriptions

Pin No.	Mnemonic	Description
1, 3, 7, 9 to 21, 30 to 40	NIC	No Internal Connection. However, these pins can be connected to RF or dc ground without affecting the performance of the device.
2, 4, 6, 24, 26, 28	GND	Ground. The GND pins must be connected to RF or dc ground.
5	RFOUT	RF Output. The RFOUT pin is ac-coupled, and maintaining a voltage standing wave ratio (VSWR) load of $\leq 2.0:1$ across frequency is recommended.
8	VCB	Buffer Supply Voltage.
22	VC4	Band 4 Supply Voltage.
23	VC3	Band 3 Supply Voltage.
25	VC2	Band 2 Supply Voltage.
27	VTUNE	Control Voltage and Modulation Input. The modulation bandwidth is dependent on the drive source impedance.
29	VC1	Band 1 Supply Voltage.
	EP	Exposed Pad. The package bottom has an exposed metal pad that must be connected to RF or dc ground.

## INTERFACE SCHEMATICS

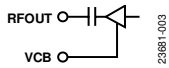


Figure 3. RFOUT and VCB Interface Schematic

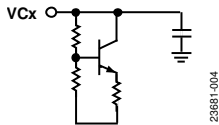


Figure 4. VC1 to VC4 Interface Schematic

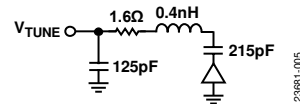


Figure 5. VTUNE Interface Schematic



Figure 6. GND Interface Schematic

# TYPICAL PERFORMANCE CHARACTERISTICS

**BAND 1: 18.10 GHz TO 20.10 GHz,  $V_{CC} = 5 V$**

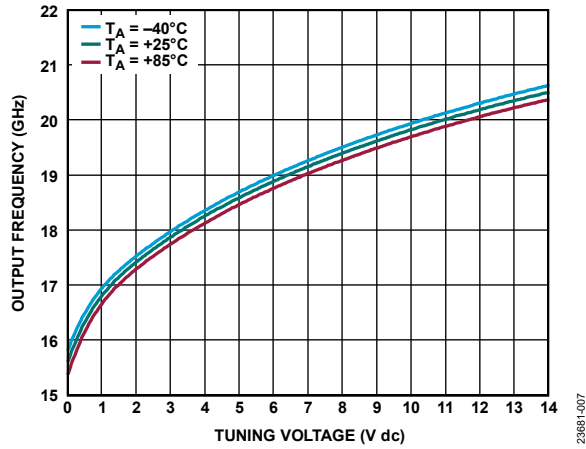


Figure 7. Output Frequency vs. Tuning Voltage for Various Temperatures

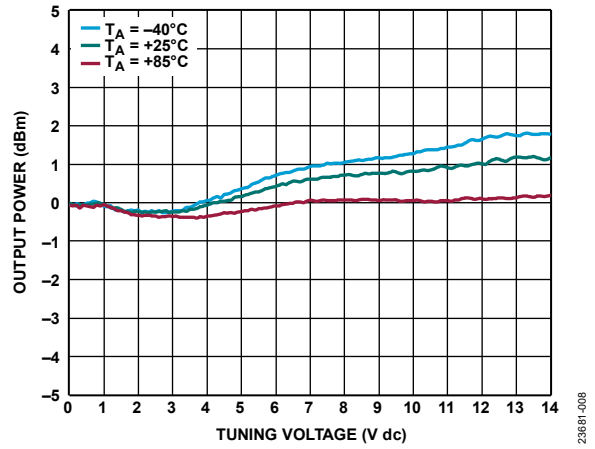


Figure 10. Output Power vs. Tuning Voltage for Various Temperatures

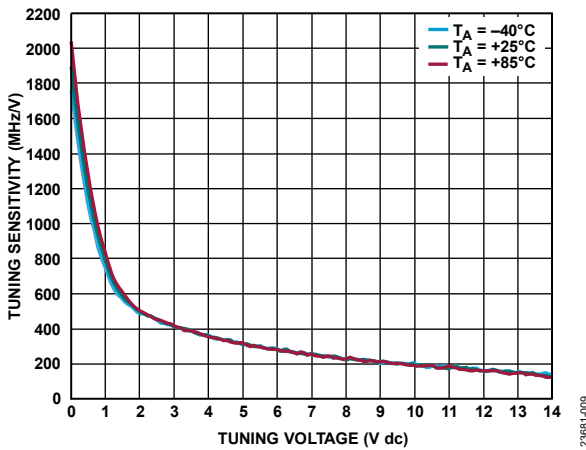


Figure 8. Tuning Sensitivity vs. Tuning Voltage for Various Temperatures

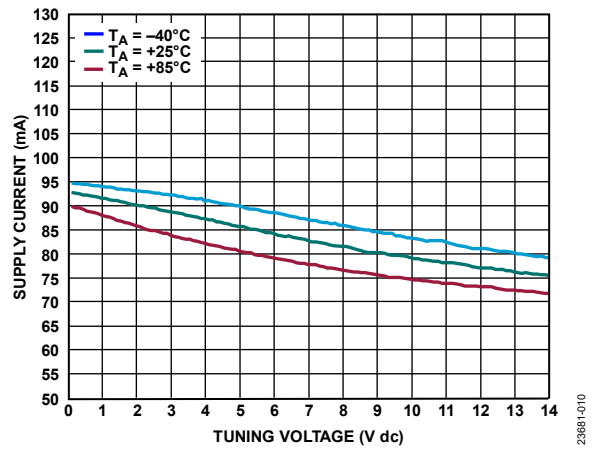


Figure 11. Supply Current vs. Tuning Voltage for Various Temperatures

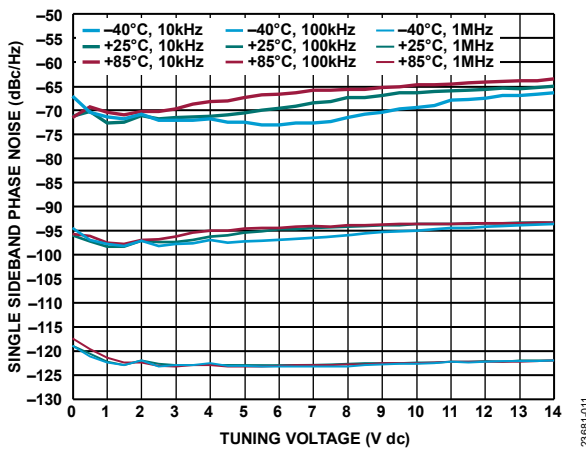


Figure 9. Single Sideband Phase Noise vs. Tuning Voltage for Various Temperatures and Frequencies

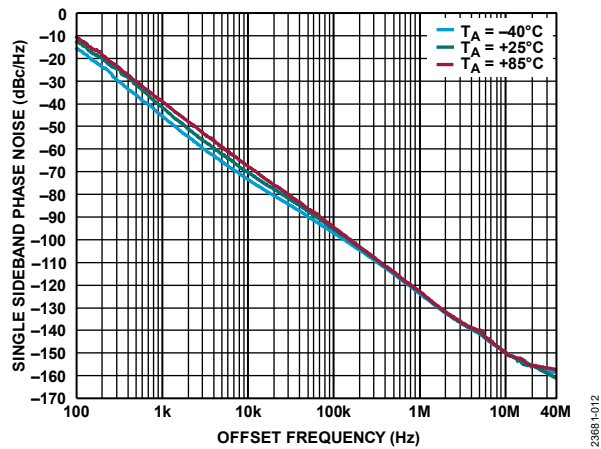


Figure 12. Single Sideband Phase Noise vs. Offset Frequency for Various Temperatures at  $V_{TUNE} = 5 V$

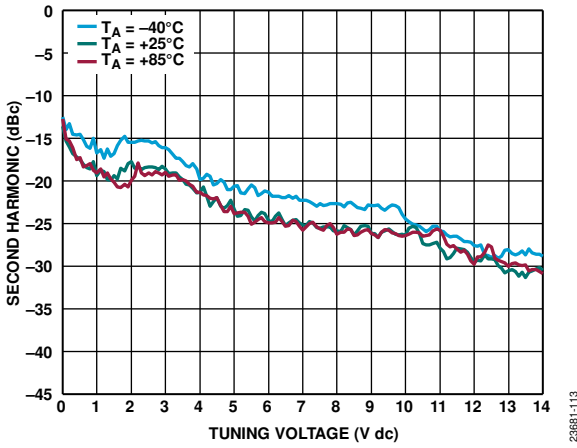


Figure 13. Second Harmonic vs. Tuning Voltage for Various Temperatures

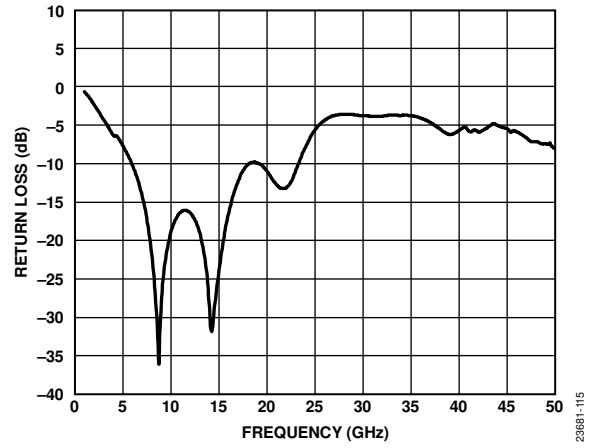


Figure 15. Return Loss vs. Frequency at  $V_{TUNE} = 6 V$

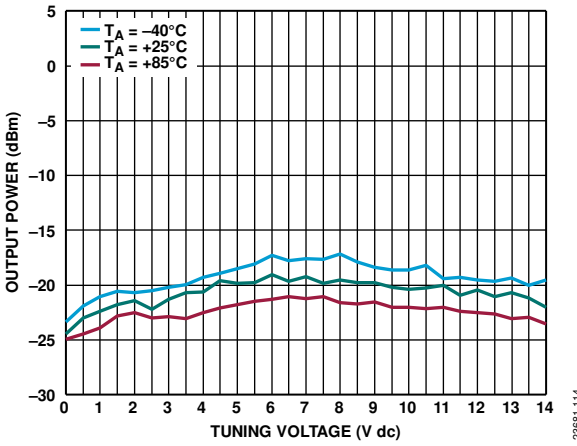


Figure 14. Output Power vs. Tuning Voltage at  $V_{CB} = 0 V$  for Various Temperatures



**BAND 2: 19.90 GHz TO 22.30 GHz,  $V_{CC} = 5 V$**

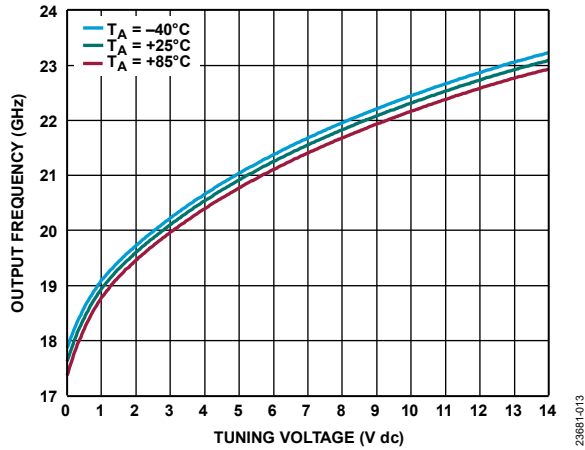


Figure 16. Output Frequency vs. Tuning Voltage for Various Temperatures

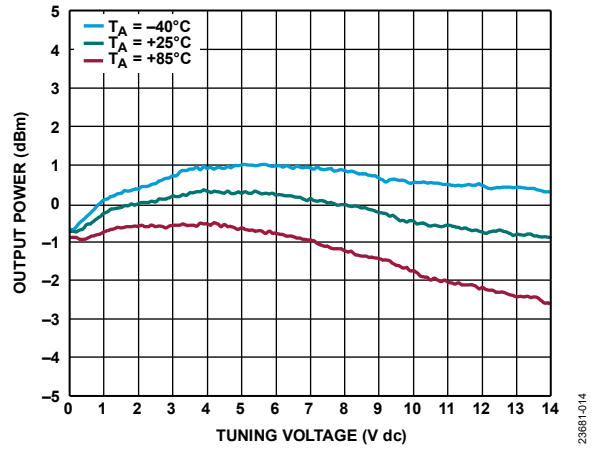


Figure 19. Output Power vs. Tuning Voltage for Various Temperatures

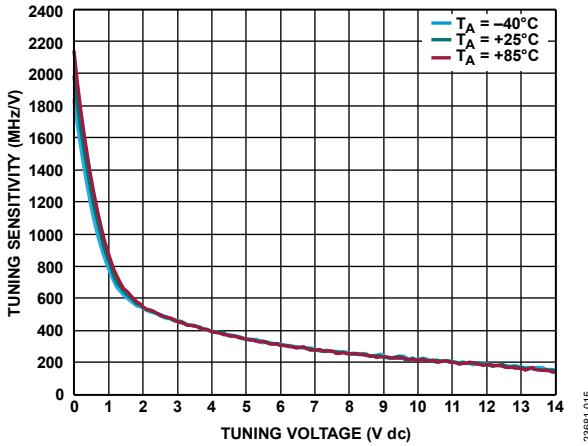


Figure 17. Tuning Sensitivity vs. Tuning Voltage for Various Temperatures

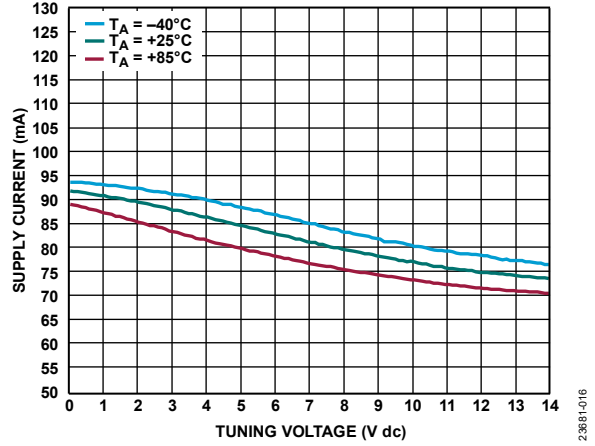


Figure 20. Supply Current vs. Tuning Voltage for Various Temperatures

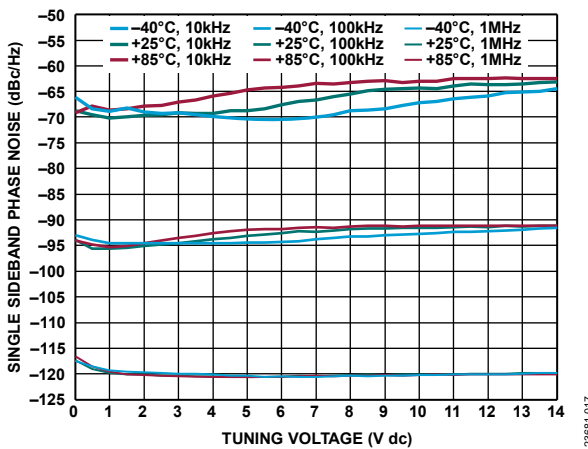


Figure 18. Single Sideband Phase Noise vs. Tuning Voltage for Various Temperatures and Frequencies

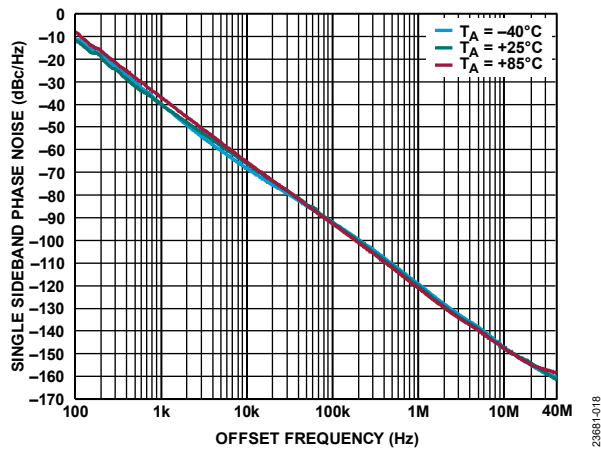


Figure 21. Single Sideband Phase Noise vs. Offset Frequency for Various Temperatures at  $V_{TUNE} = 5 V$

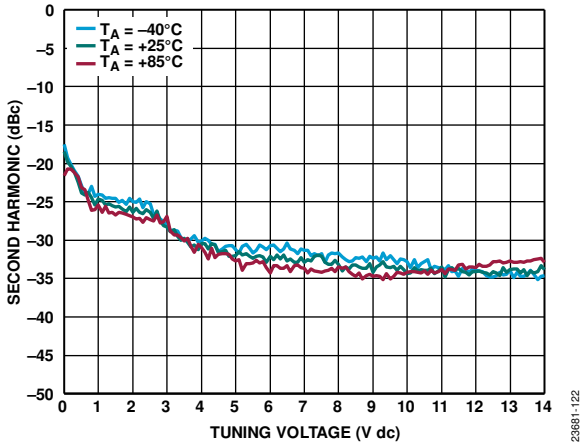


Figure 22. Second Harmonic vs. Tuning Voltage for Various Temperatures

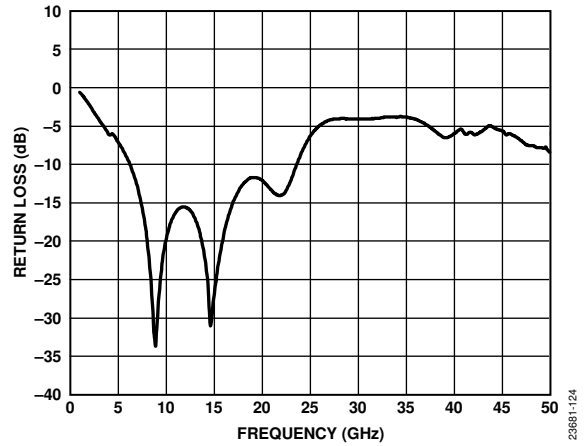


Figure 24. Return Loss vs. Frequency at  $V_{TUNE} = 6 V$

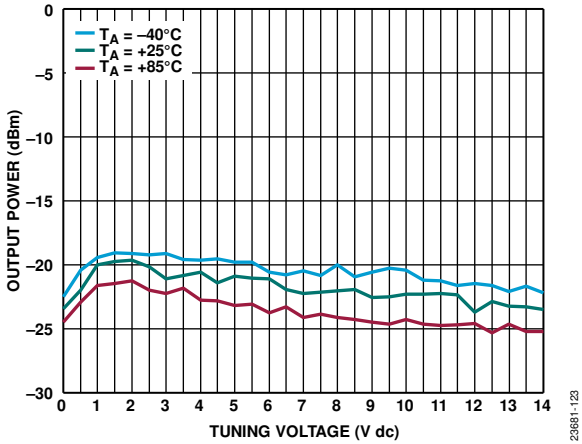


Figure 23. Output Power vs. Tuning Voltage at  $V_{CB} = 0 V$  for Various Temperatures

**BAND 3: 22.10 GHz TO 24.10 GHz,  $V_{CC} = 5 V$**

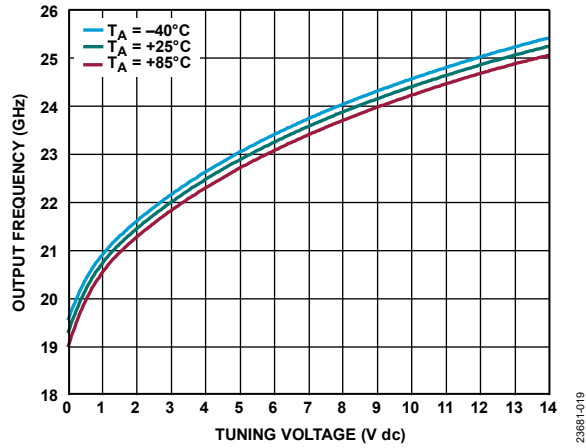


Figure 25. Output Frequency vs. Tuning Voltage for Various Temperatures

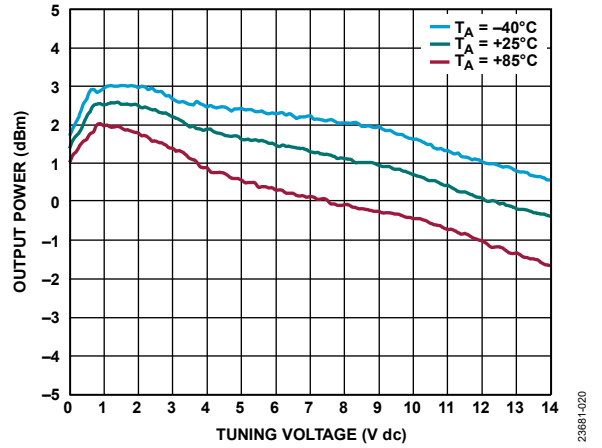


Figure 28. Output Power vs. Tuning Voltage for Various Temperatures

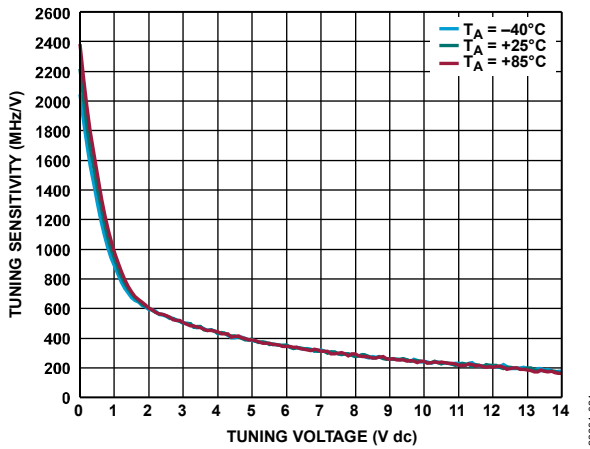


Figure 26. Tuning Sensitivity vs. Tuning Voltage for Various Temperatures

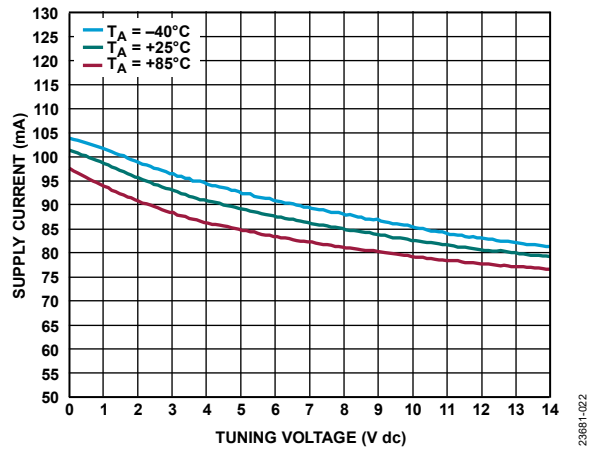


Figure 29. Supply Current vs. Tuning Voltage for Various Temperatures

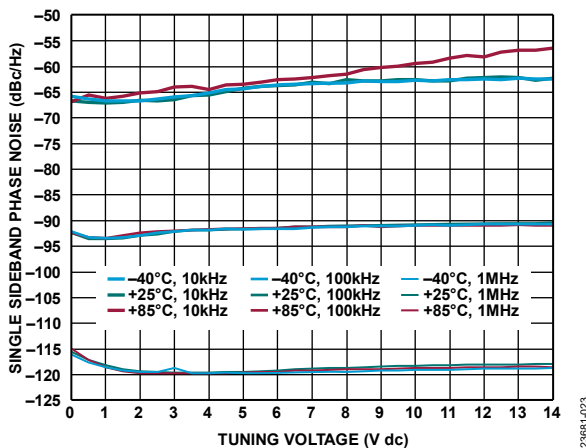


Figure 27. Single Sideband Phase Noise vs. Tuning Voltage for Various Temperatures and Frequencies

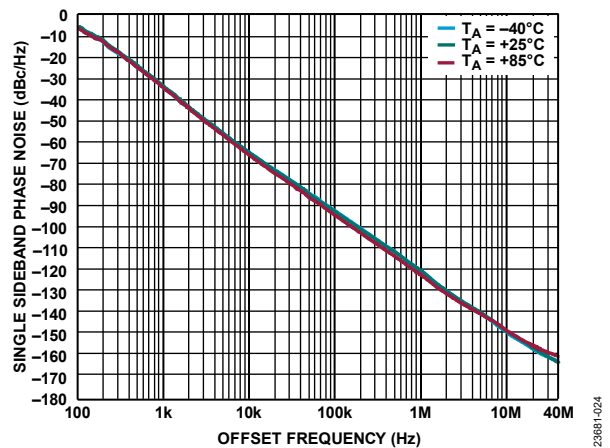


Figure 30. Single Sideband Phase Noise vs. Offset Frequency for Various Temperatures at  $V_{TUNE} = 5 V$

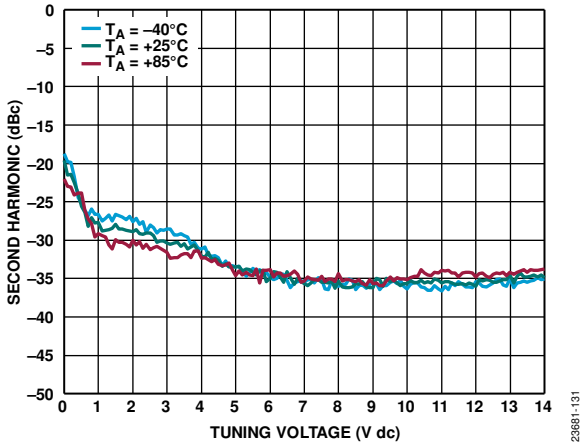


Figure 31. Second Harmonic vs. Tuning Voltage for Various Temperatures

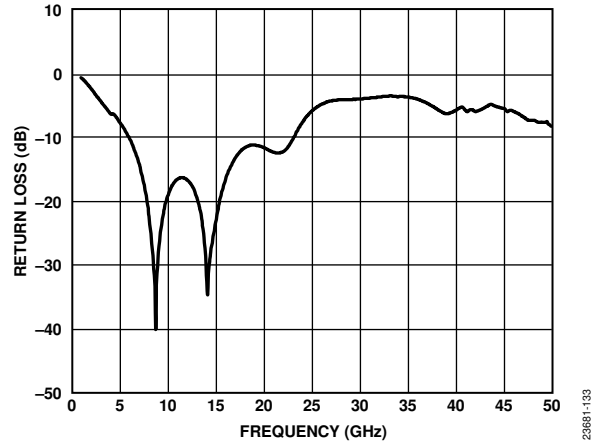


Figure 33. Return Loss vs. Frequency at  $V_{TUNE} = 6 V$

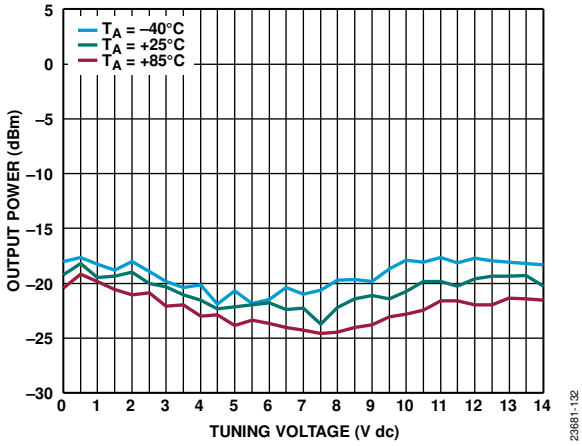


Figure 32. Output Power vs. Tuning Voltage at  $V_{CB} = 0 V$  for Various Temperatures

**BAND 4: 23.90 GHz TO 26.60 GHz,  $V_{CC} = 5 V$**

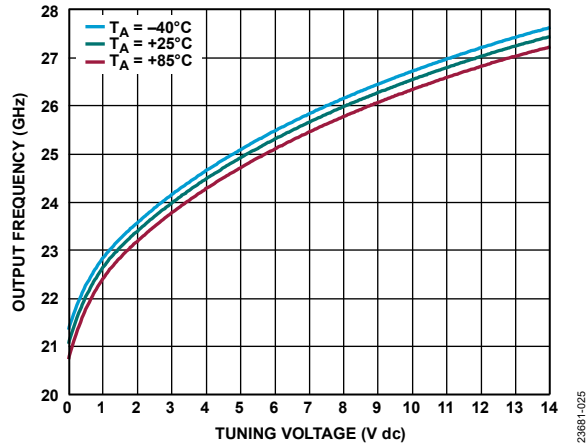


Figure 34. Output Frequency vs. Tuning Voltage for Various Temperatures

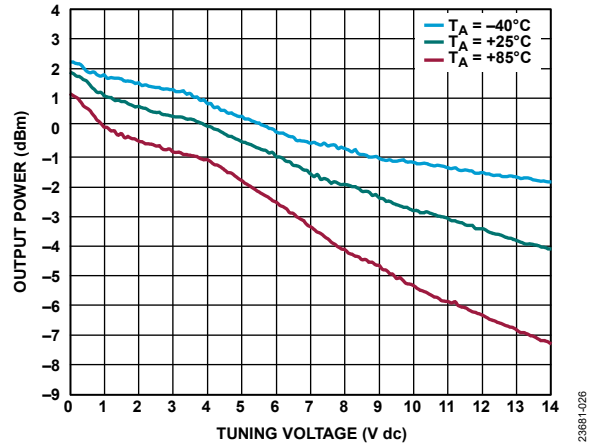


Figure 37. Output Power vs. Tuning Voltage for Various Temperatures

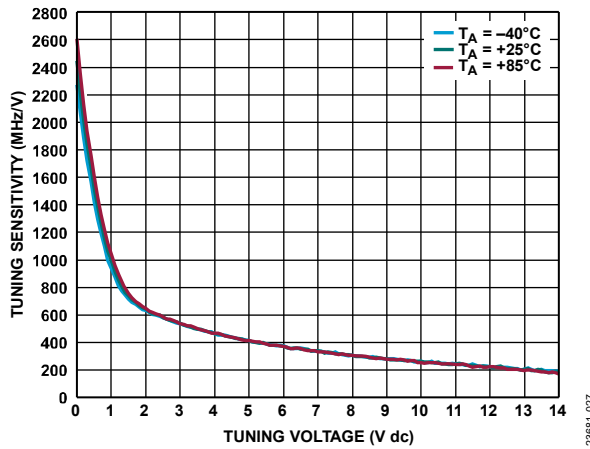


Figure 35. Tuning Sensitivity vs. Tuning Voltage for Various Temperatures

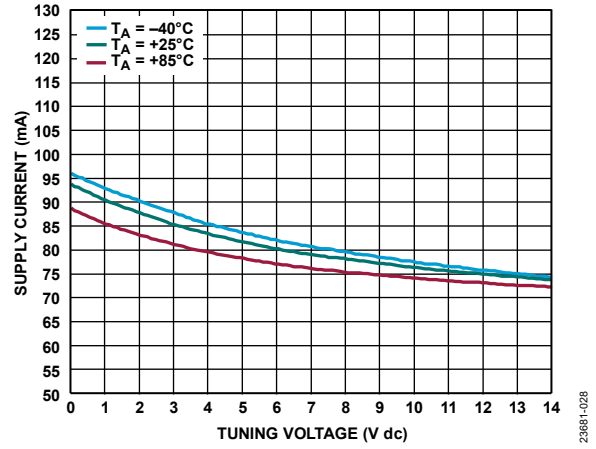


Figure 38. Supply Current vs. Tuning Voltage for Various Temperatures

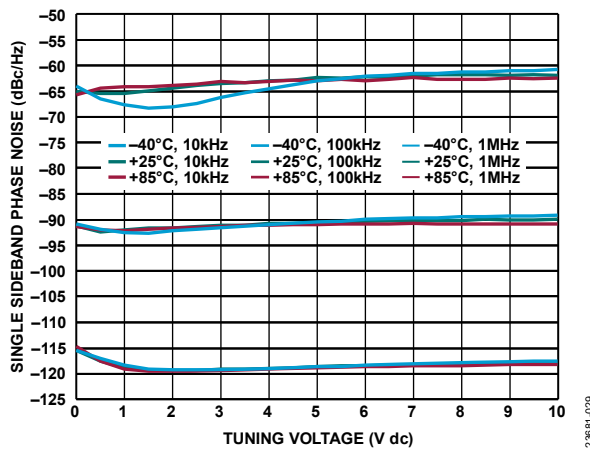


Figure 36. Single Sideband Phase Noise vs. Tuning Voltage for Various Temperatures and Frequencies (Measurement Up to 10 V Only Due to Equipment Limitation)

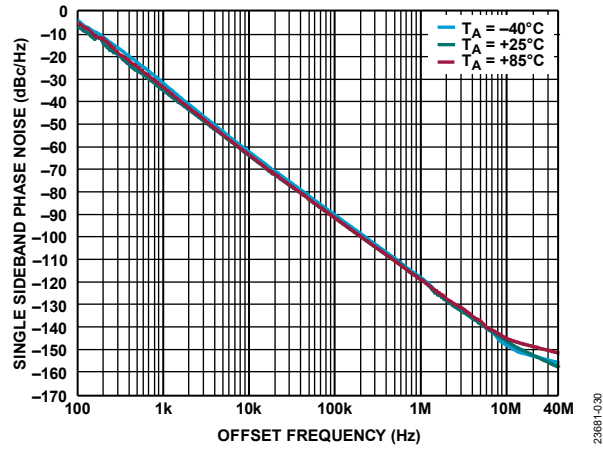


Figure 39. Single Sideband Phase Noise vs. Offset Frequency for Various Temperatures at  $V_{TUNE} = 5 V$

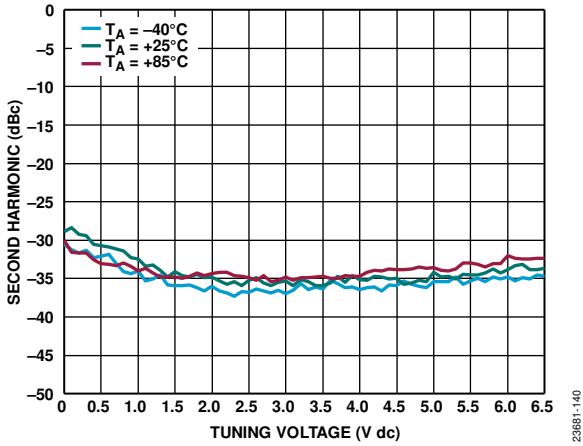


Figure 40. Second Harmonic vs. Tuning Voltage for Various Temperatures (Measurement Up to 6.5 V Only Due to Equipment Limitation)

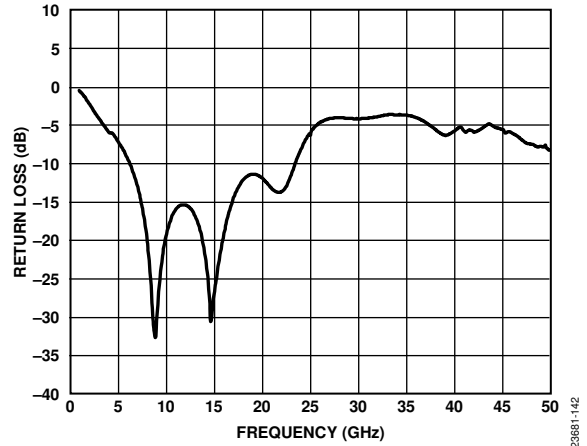


Figure 42. Return Loss vs. Frequency at  $V_{TUNE} = 6 V$

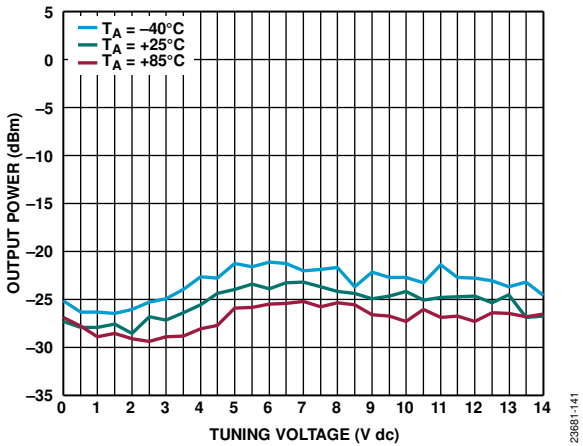


Figure 41. Output Power vs. Tuning Voltage at  $V_{CB} = 0 V$  for Various Temperatures

## THEORY OF OPERATION

The HMC8364 consists of four, fundamental VCOs with overlapping frequency ranges to ensure continuous frequency coverage from 18.10 GHz to 26.60 GHz over all conditions.

Using four oscillators instead of a single oscillator to span the frequency range reduces the percent bandwidth and tuning sensitivity of each oscillator, improving phase noise performance. Tuning sensitivity flatness across the frequency range is also improved and simplifies the loop filter design in synthesizer applications. The tuning sensitivity is similar across the four VCO cores, which means that the loop bandwidth and phase margin of the loop filter vary less overall vs. a single oscillator solution.

The four oscillators share a common tuning port, which means that even though the active devices in unused VCO cores are not biased, the resonant tanks of all four VCO cores are in

parallel and tuned simultaneously. A single buffer amplifier is also shared by all four VCOs.

The upper circuitry of the buffer amplifier is biased by VCB (Pin 8). The lower portion of the cascode buffer amplifier remains off and very little current flows until one of the VCO cores is enabled.

The lower circuitry of the amplifier is enabled when the RF signal of any one of the four VCOs arrives at its input. If VCB is biased and any VCO core is enabled, current flows through the buffer amplifier and the RF signal propagates to RFOUT (Pin 5).

The buffer amplifier is designed to support only one VCO at a time. Avoid enabling more than one oscillator at a time because multiple oscillators stress the buffer amplifier enough to reduce its long-term operating life.

## APPLICATIONS INFORMATION

The HMC8364 serves as the local oscillator (LO) in microwave synthesizer applications. The primary applications for this device are point to point and multipoint radios, military radars, test and measurement, industrial and medical equipment, and wireless communication infrastructure. The low phase noise allows higher orders of modulation and offers improved bit error rates in communication systems. Stable loop filter design is easily achieved due to the linear, monotonic tuning sensitivity across the four-VCO core, and higher output power minimizes the gain required to drive subsequent stages. The cascode output buffer amplifier stage guarantees stability over a wide range of output load conditions and improves the pulling performance of the VCO cores.

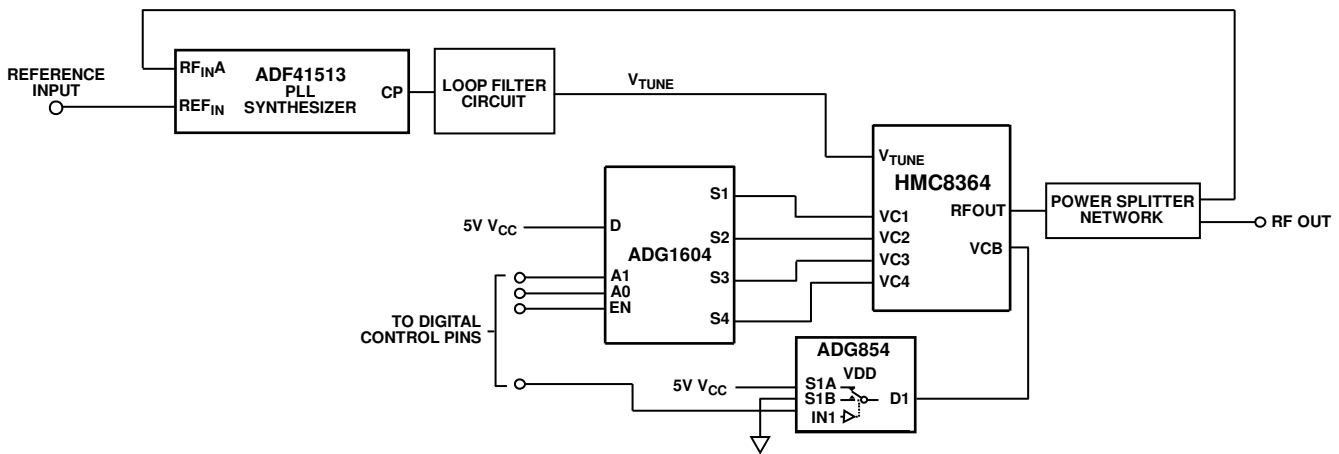
To achieve optimal performance of the VCO cores, including the lowest phase noise native to VCOs, use high power supply rejection ratio (PSRR) and low dropout (LDO) regulators to minimize any spurious frequencies from the power supply. The [ADM7150](#) and the [LT3042](#) meet these requirements and are acceptable LDO regulators to use.

The wide frequency range of the VCO cores suggests the use of a low noise, PLL synthesizer, such as the [ADF41513](#). The wide input bandwidth of the ADF41513 (1 GHz to 26.5 GHz) makes it an ideal synthesizer to be used with the HMC8364. The charge pump current can be varied up or down on the ADF41513 to compensate for VCO sensitivity variation. Many applications require actively switching between the four VCO cores as quickly as possible. Enabling more than one VCO core at a time is not recommended. Therefore, use of an appropriate 4:1 multiplexer such as the [ADG1604](#) is recommended. The

ADG1604 has low on resistance, the ability to operate with either 3 V or 5 V logic, and offers break before make switch sequencing. Alternatively, multiple [ADG854](#) switches can also be used to enable and disable the VCO cores. Although this switch also includes a break before make delay, users must prevent the possibility of powering up more than one VCO core at a time. Regardless of which approach is used to control the VCO cores, an additional ADG854 can be used to control bias to the upper portion of the cascode amplifier circuitry for use in muting the RF output (RFOUT, Pin 5) if desired. Muting RFOUT suppresses the output power by approximately 20 dB across all cores) and does not impact long-term reliability when only one VCO core is powered up at a time.

It is important to follow optimal RF layout practices for the layout of the interconnecting circuit. Give first priority to the microwave power splitter network from the output buffer of the VCO cores to the RF input pin (RF<sub>INA</sub>) of the ADF41513. Give the next highest priority to the highly sensitive V<sub>TUNE</sub> line with the first pole placed as close to the ADF41513 CP output pin as possible, and the final RC pole of the filter placed as close to the HMC8364 V<sub>TUNE</sub> pin as possible. The wide tuning range of the HMC8364 requires the use of a high voltage, low noise, operational amplifier. The [ADA4625-1](#) is acceptable to use for such applications.

The suggested PCB stackup consists of a high quality dielectric material, such as Rogers 4003. The transmission lines carrying the high frequency signal must be carefully controlled with 50 Ω characteristic impedances.



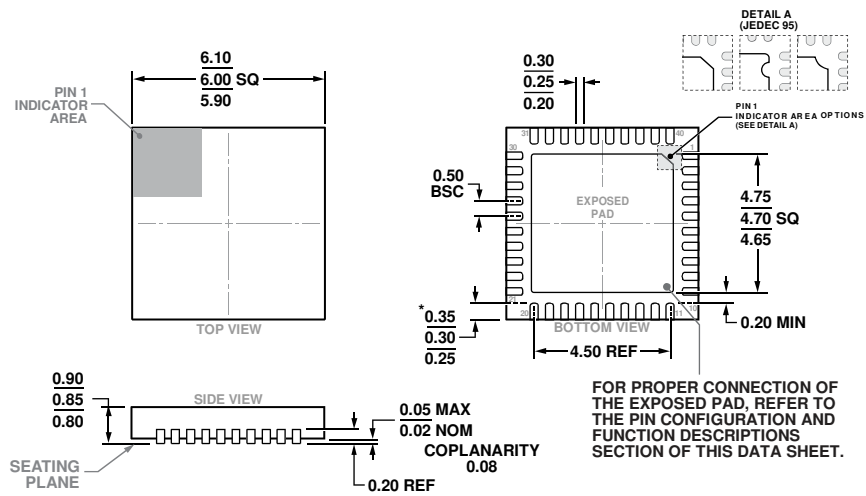
NOTES  
 1. THIS IS A SIMPLIFIED SCHEMATIC OF A TYPICAL APPLICATION DIAGRAM. PASSIVE COMPONENTS DETAILS HAVE BEEN OMITTED FOR CLARITY.

Figure 43. Typical Application Diagram

23881-143



# OUTLINE DIMENSIONS



\*COMPLIANT TO JEDEC STANDARDS MO-220-VJJD-5 WITH EXCEPTION TO LEAD LENGTH

Figure 44. 40-Lead Lead Frame Chip Scale Package [LFCSP]  
 6 mm × 6 mm Body and 0.85 mm Package Height  
 (HCP-40-1)  
 Dimensions shown in millimeters

## ORDERING GUIDE

Model <sup>1</sup>	Temperature Range	MSL Rating <sup>2</sup>	Package Description	Package Option	Ordering Quantity
HMC8364LP6GE	-40°C to +85°C	MSL3	40-Lead Lead Frame Chip Scale Package [LFCSP]	HCP-40-1	500
HMC8364LP6GETR	-40°C to +85°C	MSL3	40-Lead Lead Frame Chip Scale Package [LFCSP]	HCP-40-1	
EV1HMC8364LP6G			Evaluation Board		

<sup>1</sup> Z = RoHS Compliant Part.

<sup>2</sup> See the Absolute Maximum Ratings section.